TRENCHSTOP™ RC-Series for hard switching applications



TRENCHSTOP™ RC-Series for hard switching applications: IGBT chip with monolithically integrated diode in packages offering space saving advantage

Features

- V_{CES} = 600 V
- I_{Cn} = 15 A
- Optimised V_{CEsat} and V_F for low conduction losses
- Smooth switching performance leading to low EMI levels
- · Very tight parameter distribution
- · Operating range of 4 to 30 kHz
- Maximum junction temperature T_{vimax} = 175°C
- Short circuit capability of 5 μs
- Best in class current versus package size performance
- Complete product spectrum and PSpice Models: http://www.infineon.com/igbt/

Potential applications

- Compressors
- Pumps
- Fans

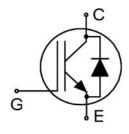
Product validation

 Technology qualified for industrial applications. Ready for validation in industrial applications according to the relevant tests of IEC 60747 and 60749 or alternatively JEDEC47/20/22

Description

Used for: Discrete components and modules

Туре	Die size	Delivery form
IGC10R60SE	2.7 mm x 3.73 mm	Sawn on foil



TRENCHSTOP™ RC-Series for hard switching applications



Table of contents

Table of contents

	Description	1
	Features	
	Potential applications	
	Product validation	
	Table of contents	
1	Mechanical parameters	
2	Characteristics	
3	Chip drawing	6
4	Chip drawing active area	
5	Bare die product specifics	
	Revision history	9
	Disclaimer	10

TRENCHSTOP™ RC-Series for hard switching applications



1 Mechanical parameters

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Table 1 Mechanical parameters

Parameter	Values		
Die size	2.7 mm x 3.73 mm		
Area total	10.07 mm ²		
Area active IGBT	5.54 mm ²		
Area active Diode	1.32 mm ²		
Emitter pad size	See chip drawing		
Gate pad size	See chip drawing		
Silicon thickness	70 μm		
Wafer size	200 mm		
Maximum possible chips per wafer	2759		
Passivation frontside	Photoimide		
Pad metal	3.2 μm AlSiCu		
Backside metal	Ni Ag - system		
Die attach	Electrically conductive epoxy glue and soft solder (temperature budget: 290°C for 1 min or 260°C for 1.5 min)		
Frontside interconnect	Wire bond: Al ≤ 350 μm		
Reject ink dot size (valid for inked delivery form only)	Ø 0.65 mm; max. 1.2 mm		
Storage environment (<6 months) for original and sealed MBB bags	Ambient atmosphere air, temperature 17°C – 25°C		
Storage environment (<6 months) for open MBB bags	Acc. IEC 62258-3; Section 9.4 Storage Environment		

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2 Characteristics

Characteristics 2

Maximum ratings Table 2

Parameter	Symbol	Note or test condition		Values	Unit	
Collector-emitter voltage	V _{CES}		T _{vj} = 25 °C	600	V	
DC collector current, limited by T _{vjmax}	I _C			_1)	А	
Pulsed collector current, t _p limited by T _{vjmax}	I _{Cpulse}			45	А	
Gate-emitter voltage	V_{GE}			±20	V	
Virtual junction temperature	$T_{\rm vj}$			-40175	°C	
Operating junction temperature	$T_{\rm vjop}$			-40175	°C	
Short-circuit withstand time ^{2) 3)}	t _{SC}	$V_{\rm CC}$ = 400 V, $V_{\rm GE}$ = 15 V	T _{vj} = 150 °C	5	μs	
Safe operating area IGBT ^{2) 3)}		$I_{C,max} = 30 \text{ A}, V_{CE} \le 600 \text{ V}, T_{vj} \le 175 \text{ °C}$		-		
Safe operating area Diode ²⁾		$I_{F,max}$ = 30 A, V_R ≤ 600 V, P_{max} = 12 kW, T_{vj} ≤ 175 °C		-		

¹⁾ Depending on thermal properties of assembly.

Static characteristics (tested on wafer), Tvj = 25°C Table 3

Parameter	Symbol	Note or test condition		Values		
			Min.	Тур.	Max.	
Collector-emitter breakdown voltage	V _{BRCES}	$I_{\rm C} = 0.2 \text{ mA}, V_{\rm GE} = 0 \text{ V}$	600			V
Collector-emitter saturation voltage	V _{CEsat}	$V_{\rm GE} = 15 \text{V}, I_{\rm C} = 15 \text{A}$	1.88	2.2	2.62	V
Reverse diode forward voltage	V_{F}	$I_{\rm F} = 15 \text{ A}, V_{\rm GE} = 0 \text{ V}$	1.68	2.1	2.42	V
Gate-emitter threshold voltage	V_{GEth}	$I_{C} = 255 \mu\text{A}, V_{GE} = V_{CE}$	4.4	5	5.6	V
Zero gate-voltage collector current	I _{CES}	$V_{CE} = 600 \text{ V}, V_{GE} = 0 \text{ V}$			2	μΑ
Gate-emitter leakage current	I _{GES}	$V_{CE} = 0 \text{ V}, V_{GE} = 20 \text{ V}$			120	nA

Not subject to production test - verified by design/characterization.

²⁾ 3) Allowed number of short circuits: <1000; time between short circuits: >1s.

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2 Characteristics

Table 4Electrical characteristics

Parameter	Symbol	Symbol Note or test condition		Values			Unit
				Min.	Тур.	Max.	
Collector-emitter saturation voltage	V _{CEsat}	$V_{\rm GE} = 15 \text{V}, I_{\rm C} = 15 \text{A}$	T _{vj} = 175 °C		2.3		V
Input capacitance	C _{ies}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 10$	00 kHz, $T_{\rm vj}$ = 25 °C		961		pF
Output capacitance	C _{oes}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 10$	00 kHz, T _{vj} = 25 °C		53		pF
Reverse transfer capacitance	C _{res}	$V_{\text{CE}} = 25 \text{ V}, V_{\text{GE}} = 0 \text{ V}, f = 10$	00 kHz, $T_{\rm vj}$ = 25 °C		33		pF

Note: Electrical Characteristic, not subject to production test - verified by design/characterization

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3 Chip drawing

3 Chip drawing

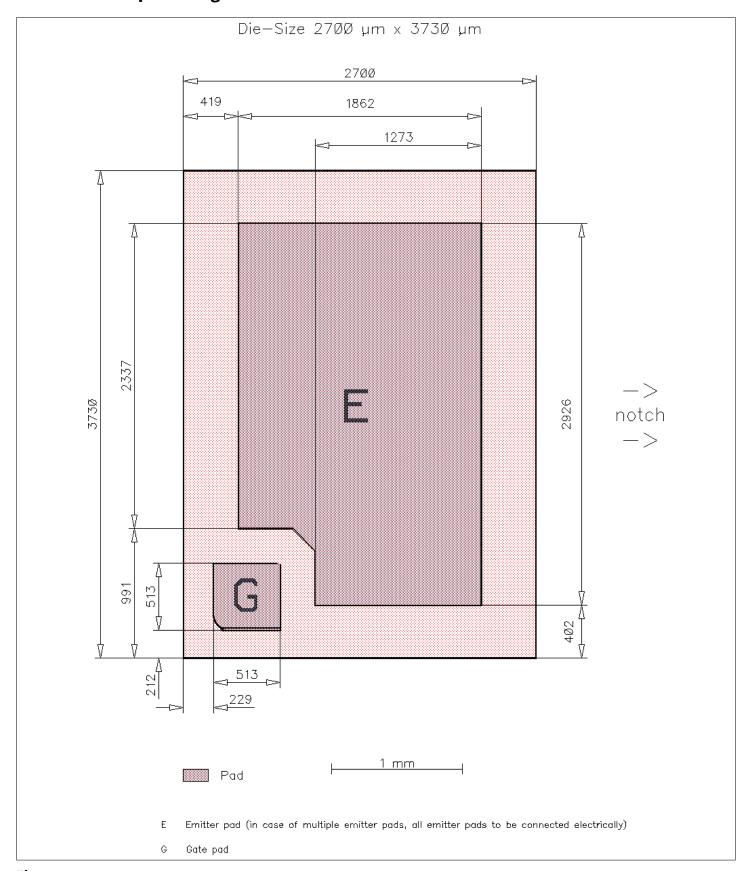


Figure 1

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4 Chip drawing active area

4 Chip drawing active area

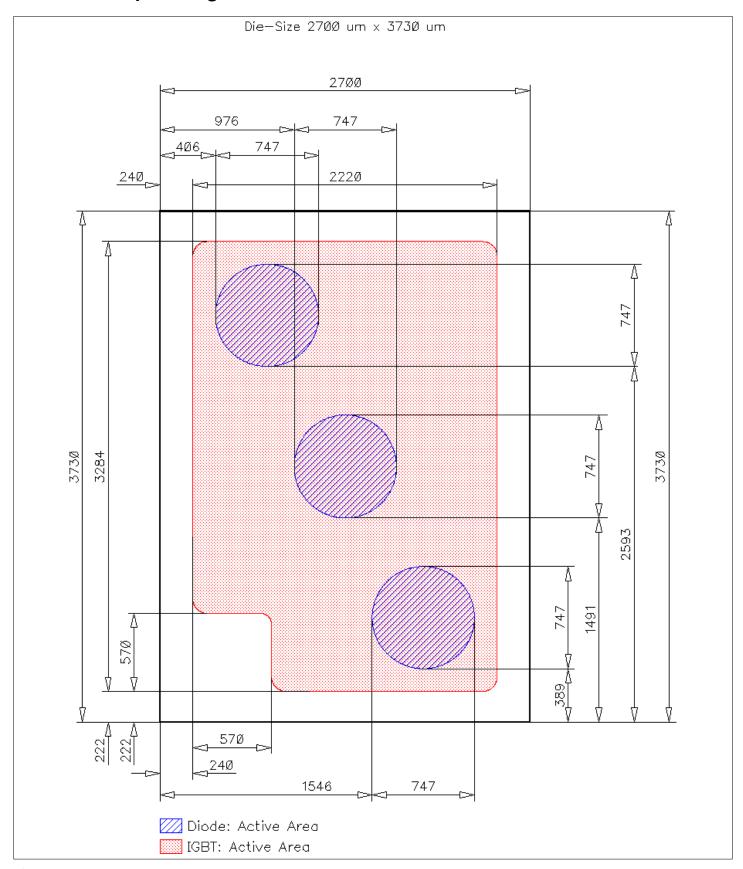


Figure 2

TRENCHSTOP™ RC-Series for hard switching applications



5 Bare die product specifics

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- Switching characteristics and thermal properties are depending strongly on package design and mounting technology and can therefore not be specified for a bare die.
- Test coverage at wafer level cannot cover all application conditions. Therefore, it is recommended to test all characteristics, which are relevant for the application at package level, including RBSOA and SCSOA.
- AQL 0.65 for visual inspection according to failure catalogue.
- Electrostatic discharge sensitive device according to MIL-STD 883.
- Further technical information about the performance of this chip in package PG-TO252-3 is given exemplarily at www.infineon.com/igbt. The chip qualification is independent of the qualification which is performed for the Discretes.
- The example application may be subject to change without prior notice. It is intended for information purposes only, and should not be interpreted as a commitment.
- Example application: IKD15N60RF

Datasheet 8

TRENCHSTOP™ RC-Series for hard switching applications



Revision history

Revision history

Document revision	Date of release	Description of changes
1.00	2023-06-07	Final datasheet
		Legacy Revisions
		V1.0 19.06.2013

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Edition 2023-06-07 Published by Infineon Technologies AG 81726 Munich, Germany

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Document reference IFX-AAT250-001

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